Supporting Information

Regulating the Electronic States of NiSe₂ by Cr-doping to Promote Formation of Active Phase for High Catalytic Performance of Urea Oxidation Reaction

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Experimental section

Chemical reagents and materials

The chemical reagents and materials utilized in this work were all received from the manufacturer. Selenium (Se power, 99.99%, Macklin) was acquired from Shanghai Macklin Biochemical Technology Co., LTD. Chromium(III) nitrate nonahydrate ($CrN_3O_9 \cdot 9H_2O$, 99.0%, Aladdin) was sourced from Shanghai Aladdin Biochemical Technology Co Ltd. Urea (H_2NCONH_2 , 99%, Aladdin) was sourced from Shanghai Aladdin Biochemical Technology Co Ltd. Nickel(II) nitrate hexahydrate ($Ni(NO_3)_2 \cdot 6H_2O$, AR, Keshi) was procured from Chengdu Chron Chemicals Co., LTD. Nickel foam (NF) was procured from Shenzhen Kejing Zhida Technology Co., LTD. The NF's thickness measured 1.6 mm, and its surface density was 350 g·m⁻². Deionized (DI) and ultra-pure water were generated by an ultrapure water system. All reagents were employed without additional purification.

Methods

Firstly, NF (1 cm \times 2 cm) was soaked in 3.0 M HCl solution for ultrasonic cleaning for 15 min, followed by ultrasonic cleaning in ethanol and UP water for 15 min to remove oxide impurities on NF. The specific

experimental steps were as follows: 1 mmol Ni(NO₃)·6H₂O, *x* mmol Cr(NO₃)₃·9H₂O (x=0.1, 0.25, 0.4), and 0.2 g CO(NH₂)₂ are dissolved in 30 mL of deionized water and stirred evenly for 30 min, and then transferred to a 50 mL stainless steel PTFE autoclave. Then place three pieces of the pretreated NF sheets in a reaction vessel and maintain at 150 °C for 12 h. After natural cooling, the samples were washed several times with deionized water after room temperature, and were dried in a vacuum drying oven at 60 °C for 4 h to obtain Cr_x-Ni(OH)₂. Finally, the obtained Cr_x-Ni(OH)₂ and 0.4 g selenium powder were placed downstream and upstream of the quartz tube, respectively, and calcined at 300 °C for 2 h at a heating rate of 5 °C min⁻¹ under nitrogen conditions. After cooling to room temperature, Cr_x-NiSe₂ (x = 0.1, 0.25, 0.4) is obtained. For comparison, Cr-NiO and NiSe₂ were prepared using similar synthesis methods, but they were obtained without Se and Cr, respectively.

1. Structural characterizations

In X-ray diffraction (XRD) testing, samples are scraped from NF to rule out the influence of Ni substrate. The XRD data of the sample was obtained by using a Bruker D8 X-ray diffraction device with a tube voltage of 40 KV in the range of $2\theta = 10$ ~80°. Field emission scanning electron microscopy (SEM) measurements are performed by using a Thermo field Quattro S instrument to examine the surface morphology of the samples. High-resolution transmission electron microscopy (HRTEM) and transmission electron microscopy (TEM) were used to observe the microstructure details and elemental distribution of the material (JEM-F200). Thermo Fisher Scientific K-Alpha X-ray photoelectron spectroscopy (XPS) was used to investigate the valence state and chemical composition of the samples. Raman spectra were collected by using HORIBA XploRA Plus Raman imaging spectrometer, with a laser source wavelength of 532 nm, under natural conditions. Prior to testing, a 520 cm⁻¹ Raman peak of the silicon wafer was used for correction. In in-situ Raman measurements, Pt wire and Hg/HgO electrodes were used as the opposite electrode and the reference electrode, respectively. The controlled potential was applied to the catalyst in 1.0 M KOH+0.33 M urea solution, and Raman data was obtained at different potentials.

2. Electrochemical measurements

The electrochemical properties were measured by CHI 760E and CHI 660E electrochemical workstations. At room temperature, a standard three-electrode system was assembled with the self-supported electrodes (such

as $Cr_{0.25}$ -NiSe₂, NiSe₂, Cr-NiO) of loaded NF sample as the working electrode, graphite plate as the counterelectrode and Hg/HgO electrode as the reference electrode. Unless otherwise noted, the electrolyte was 1.0 M KOH+0.33 M urea solution with a pH of 14. For all samples, 80 cycles were performed to activate them by cyclic voltammetry (CV) at a rate of 100 mV s⁻¹ in the voltage range 0~1.0 V (*vs.* Hg/HgO). Subsequently, linear sweep voltammetry (LSV) was performed at a scan rate of 5 mV s⁻¹, with 95%-*i*R correction compensated manually. Potential E (*RHE*) and overpotential η were calculated by the following formula:

$$E_{RHE} = E_{Hg/HgO} + 0.0592 \text{pH} + 0.098 \text{ V}$$
(1)
$$\eta = E_{RHE} - 1.23$$
(2)

The Tafel slope (b) was obtained from the LSV curve by using the Tafel equation:

$$\eta = b\log(j) + a \tag{3}$$

Where η is the overpotential and j is the corresponding current density. Cyclic voltammetry (CV) among -0.1 ~0.1 V vs. *RHE* was used to assess the electrochemical active area at the scan rates of 2, 4, 6, 8 and 10 mV s⁻¹ under the electric double layer capacitor (C_{dl}). The equation is as follows:

$$C_{\rm dl} = \frac{ja - jc}{2v} \tag{4}$$

Where v is the scanning rate, j_a is the positive scanning current density at 0 V (vs. Hg/HgO), and j_c is the negative scanning current density at 0 V (vs. Hg/HgO). Electrochemical impedance spectroscopy (EIS) was measured in the 0.01~100 kHz frequency range, the ac voltage was 5 mV, and the voltage was 1.4 V vs. *RHE*. The long-term durability of the catalyst was tested at constant current densities of 10 mA cm⁻² and 100 mA cm⁻² for 100 hours.

3. DFT methods

In the present study, all computational tasks were executed utilizing the DMol3 module within Materials Studio3.¹ [Delley, B. An all-electron numerical method for solving the local density functional for polyatomic molecules. *J. Chem. Phys.* 92, 508-517 (1990).] Upon achieving an energy convergence tolerance of 1×10^{-5} Hartree, a maximum force convergence threshold of 0.004 Hartree per Angstrom (1 Angstrom being equivalent to 1×10^{-10} meters), and a maximum displacement convergence of 0.005 Angstrom. The pertinent energy calculations and geometric structure optimizations were deemed complete. The electron exchange and correlation functions were modeled using the Perdew-Burke-Ernzerhof (PBE) generalized gradient

approximation (GGA) functional.² [Perdew, J. P. Generalized gradient approximations for exchange and correlation: A look backward and forward. *Phys. B* 172, 1-6 (1991).] A vacuum slab with a thickness of 15 Angstroms was employed to segregate the surface, thereby preventing inter-layer interactions, with the symmetry parameters set to none and spin polarization configured as Collinear. The Brillouin zone's k-point was established at $2 \times 2 \times 1$, and a global orbital cutoff radius of 4.4 Angstroms was implemented.

The adsorption energy (Eads) of urea intermediates for all models is calculated according to the following formula:

$$\Delta E_{\rm ads} = E_{\rm oxy/mod} - E_{\rm oxy} - E_{\rm mod}$$
 (5)

Where ΔE_{ads} represents the adsorption energy of urea intermediates on active site, $E_{oxy/mod}$ represents the total energy of the model with urea intermediates, and E_{oxy} represents the energy of oxygen intermediates. E_{mod} is the energy of models. The free energy (ΔG) of the reaction steps is calculated by using the calculated hydrogen electrode model. The ΔG of the reaction step is calculated as follows:

$$\Delta G = \Delta E_{ads} + \Delta E_{ZPE} + T\Delta S \tag{6}$$

Where ΔE_{ZPE} is he differences in the zero-point energy, ΔS is the change of entropy, and T is the temperature (T = 298 K), respectively.



Fig. S1. (a-b) SEM images of $NiSe_2$ with different magnifications.



Fig. S2. (a-b) SEM images of $Cr_{0.1}$ -NiSe₂ with different magnifications; (c-d) SEM images of $Cr_{0.4}$ -NiSe₂ with different magnifications.



Fig. S3. N_2 adsorption/desorption isotherms of NiSe₂ and Cr_{0.25}-NiSe₂.



Fig. S4. XRD pattern of Cr-NiO sample.



Fig. S5. XPS survey spectra of (a) NiSe₂, and (b) Cr_{0.25}-NiSe₂.



Fig. S6. High-resolution XPS spectra of Ni 2p of Cr_{0.1}-NiSe₂, Cr_{0.25}-NiSe₂, and Cr_{0.4}-NiSe₂.



Fig. S7. High-resolution XPS spectra of Se 3d of Cr_{0.1}-NiSe₂, Cr_{0.25}-NiSe₂, and Cr_{0.4}-NiSe₂.



Fig. S8. High-resolution XPS spectra of Cr 2p of Cr_{0.1}-NiSe₂, Cr_{0.25}-NiSe₂, and Cr_{0.4}-NiSe₂.



Fig. S9. (a) Cyclic voltammograms of NiSe₂ in 1 M KOH+0.33 M urea solution at different scan rates; (b) Plot of the logarithm of cathodic peak current density (j_c) against the logarithm of scan rate (v).

The given cathode current density j_c and the sweep rate v obey a power-law relationship: $j_c=av^{b,3,4}$ where a and b are both adjustable parameters, and the b value is determined by the slope of the Log j_c vs Logv curve. There are two limit cases, b = 0.5 and b = 1. (i) when b = 0.5, it indicates that the redox process is controlled by diffusion; (ii) When it is a fully non-diffusion-controlled capacitive behavior, b = 1. Combined with Fig.

S9, the b value is 0.7005, indicating that the redox characteristics are related to the mixed control of diffusion and capacitance behavior, similar to $Cr_{0.25}$ -NiSe₂.



Fig. S10. (a) LSV curves and (b) Tafel plots of Cr_{0.1}-NiSe₂, Cr_{0.25}-NiSe₂, and Cr_{0.4}-NiSe₂ samples in 1.0 M KOH+0.33 M urea.



Fig. S11. (a) LSV curves and (b) Tafel plots of $Cr_{0.25}$ -NiSe₂ sample in 1.0 M KOH+0.33 M urea ($Cr_{0.25}$ -NiSe₂ sample were obtained at different selenization temperature of 250°C, 300 °C, 350 °C, 400 °C and 500 °C).



Fig. S12. CVs of (a) Cr_{0.25}-NiSe₂, (b) NiSe₂, (c) Cr-NiO, and (d) NF at different scan rates from 2 to 10 mVs⁻¹.



Fig. S13. Stability test of $Cr_{0.25}$ -NiSe₂ at j = 20 mA cm⁻² in 1.0 M KOH+0.33 M urea ("fresh" indicates the replacement of the electrolyte).



Fig. S14. Schematic diagram of crystal structure of $NiSe_2$ and $Cr_{0.25}$ - $NiSe_2$.

Table S1. Impedance fitting results of as-prepared $Cr_{0.25}$ -NiSe2 comparing with different catalytic electrodes,the impedance test was carried out in a solution of 1 M KOH with 0.33 M urea.

	Cr _{0.25} -NiSe ₂	NiSe ₂	Cr-NiO	NF
Rs (Ω)	1.342	1.184	1.256	1.031
Rct (Ω)	4.213	5.024	4.904	17.65

Table S2. Comparison of UOR performances of $Cr_{0.25}$ -NiSe₂ with other recently reported transition metal chalcogenides catalysts.

catalyst	Potential (V vs. RHE) for 100 mA cm ⁻²	Tafel slope (mV dec ⁻¹)	Electrolyte	Ref
Cr _{0.25} -NiSe ₂	1.37	13.2	1 M KOH + 0.33 M Urea	This work
CoFeCr LDH/NF	1.4	85	1M KOH + 0.33 M Urea	5
NiSe ₂ /MoSe ₂	1.38	20.13	1 M KOH + 0.5 M Urea	6
MoSe ₂ /NiSe ₂	1.47	68	1.M KOH + 0.5 M Urea	7
Ni-TPA@NiSe/NF	1.37	22.7	1.M KOH + 0.5 M Urea	8
NiCoCr-LDH/NF	1.38	18.61	1.M KOH + 0.5 M Urea	9
NiSe@Ni1 ₂ P ₅ /NCF	1.412	53.65	1.M KOH + 0.5 M Urea	10
Cr-Ni(OH) ₂	1.38	14	1.M KOH + 0.33 M Urea	11
Fe–Ni ₂ PNiSe ₂ -12	1.39	28	1.M KOH + 0.33 M Urea	12
$Cr \cdot P-NiMoO_4@NF$	1.39	8.12	1.M KOH + 0.5 M Urea	13
PBA@MOF-Ni/Se	1.42	64	1.M KOH + 0.5 M Urea	14
Ni _{0.86} Se-NiSe ₂ @NC-2	1.41	64.4	1M KOH + 0.33 M Urea	15
Ni ₃ S ₃ -Cr(OH) ₃ - Ti ₃ C ₂ @NF	1.38	14.99	1.M KOH + 0.5 M Urea	16

Table S3.	Comparison	of the	overall	urea	splitting	performance	of	$Cr_{0.25}$ -NiSe ₂ I	Pt/C	with 1	the	reported
catalysts.												

catalyst	Potential (V) for 10 mA cm ⁻²	Stability (h)	Ref
Cr _{0.25} -NiSe ₂ Pt/C	1.42	20	This work
a-FeCoO	1.54	36	17
Ce-NiVS	1.55	15	18
Cu-doped Ni ₃ S ₂ /NF	1.57	-	19
NiS/MoS ₂ @CC	1.46	25	20
N-NiS/NiS ₂	1.61	8	21
NP-Ni _{0.7} Fe _{0.3}	1.55	10	22
V-Co ₂ P ₄ O ₁₂ /CC	1.42	20	23

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